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parts of the IEC 60747 series, and with some necessary additions;

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IEC 60747 -16-5 edition 1.1 contains the first edition (2013-06) [documents 47E/452/FDIS and 47E/454/RVD] and its amendment 1 (7) [documents 2020-047E/673/CDV and 47E/705/RVC] and its corrigendum (2020-09). In this Redline version, a vertical line in the margin shows where the technical content is modified by amendment 1. Additions are in green text, deletions are in strikethrough red text.
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c) The text of the second edition was combined with that of IEC 60747-7-5. This publication is to be read in conjunction with IEC 60747-1:2006. This publication is to be read in conjunction with IEC 60747-1:2006.

IEC 60747-7:2010 - Estonian Centre for Standardisation

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b) Clauses 3, 4, 5 and 7 were amended with some deletions of information no longer in use or already included in other parts of the IEC 60747 series, and with some necessary additions; c) Clause 6 was moved and added to Clause 7 of this third edition; d) some parts of Clause 7 were moved and added to Clause 7 of this third edition;

IEC 60747-2 Ed. 3.0 b:2016

b) "Clause 4 Terminology and letter symbols" was divided into "Clause 3 Terms and definitions" and "Clause 4 Letter symbols" was amended with additions and deletions. c) Clause 5, 6 and 7 were amended with necessary additions and deletions. This publication is to be read in conjunction with IEC 60747-1:2006.

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